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Features

FAIRCHILD

- Max $r_{DS(on)}$ = 14.5 m Ω at V_{GS} = 4.5 V, I_D = 9.4 A
- Max r_{DS(on)} = 18.2 mΩ at V_{GS} = 2.5 V, I_D = 8.3 A
- Max $r_{DS(on)}$ = 23.3 m Ω at V_{GS} = 1.8 V, I_D = 7.3 A
- Max $r_{DS(on)}$ = 32.3 m Ω at V_{GS} = 1.5 V, I_D = 6.2 A
- Low Profile-0.8 mm maximum in the new package MicroFET 2x2 mm
- RoHS Compliant

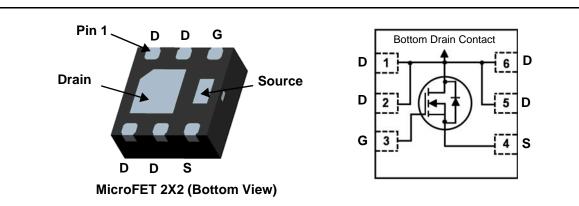


General Description

This Single N-Channel MOSFET has been designed using Fairchild Semiconductor's advanced Power Trench[®] process to optimize the $r_{\text{DS(ON)}}$ @ V_{GS} = 1.5 V on special MicroFET leadframe.

Applications

- Li-lon Battery Pack
- DC-DC Buck Converters



MOSFET Maximum Ratings TA = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units	
V _{DS}	Drain to Source Voltage	20	V			
V _{GS}	Gate to Source Voltage			±8	V	
ID	-Continuous	T _A = 25 °C	(Note 1a)	9.4	^	
	-Pulsed			54	— A	
P _D	Power Dissipation	T _A = 25 °C	(Note 1a)	1.9	14/	
	Power Dissipation $T_A = 25 \text{ °C}$ (Note 1b)		(Note 1b)	0.7	W	
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C	

Thermal Characteristics

R_{\thetaJA}	Thermal Resistance, Junction to Ambient	(Note 1a)	65	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	(Note 1b)	180	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
104	FDMA7628	MicroFET 2X2	7 "	12 mm	3000 units

May 2012

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Off Chara	cteristics						
BV _{DSS}	Drain to Source Breakdown Voltage	I _D = 250 μA, V _{GS} = 0 V	20			V	
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, referenced to 25 °C		15		mV/°C	
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 16 V, V _{GS} = 0 V			1	μA	
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 8 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±100	nA	
On Chara	cteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250 μA	0.4	0.6	1.0	V	
$\frac{\Delta V_{GS(th)}}{\Delta T_{J}}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C	-	-3		mV/°C	
0		V _{GS} = 4.5 V, I _D = 9.4 A		11.3	14.5	_	
		$V_{GS} = 2.5 \text{ V}, I_D = 8.3 \text{ A}$		12.7	18.2		
r _{DS(on)}	Static Drain to Source On Resistance	V _{GS} = 1.8 V, I _D = 7.3 A		15.0	23.3	mΩ	
		$V_{GS} = 1.5 \text{ V}, I_D = 6.2 \text{ A}$		18.3	32.3		
		$V_{GS} = 4.5 \text{ V}, I_D = 9.4 \text{ A},$ $T_J = 125 \text{ °C}$		14.7	18.3		
9 _{FS}	Forward Transconductance	$V_{DD} = 5 \text{ V}, \ \text{I}_{D} = 9.4 \text{ A}$		56		S	
Dvnamic	Characteristics						
C _{iss}	Input Capacitance			1260	1680	pF	
C _{oss}	Output Capacitance	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 0 \text{ V},$		180	240	pF	
C _{rss}	Reverse Transfer Capacitance	f = 1 MHz		122	185	pF	
R _q	Gate Resistance			1.9		Ω	
0	Characteristics				1	1	
t _{d(on)}	Turn-On Delay Time			9	17	ns	
t _r	Rise Time	V _{DD} = 10 V, I _D = 9.4 A,		6	11	ns	
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 4.5 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		37	58	ns	
t _f	Fall Time			6	11	ns	
	Total Gate Charge	$V_{GS} = 0 V \text{ to } 4.5 V$		17.5		nC	
0	Total Gate Charge	$V_{GS} = 0 V \text{ to } 2.5 V$		10.0		nC	
Qg	Total Gate Charge	$V_{GS} = 0 \text{ V to } 1.8 \text{ V} \text{ V}_{DD} = 10 \text{ V},$		7.4		nC	
	Total Gate Charge	$V_{GS} = 0 V \text{ to } 1.5 V I_D = 9.4 \text{ A}$		6.2		nC	
Q _{gs}	Gate to Source Charge			1.7		nC	
Q _{gd}	Gate to Drain "Miller" Charge			2.7		nC	

۱ _S	Maximum Continuous Drain-Source Diode Forward Current				2.0	A
V _{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = 2.0 A$ (Note 2)		0.63	1.2	V
t _{rr}	Reverse Recovery Time	I _E = 9.4 A, di/dt = 100 A/μs		16	29	ns
Q _{rr}	Reverse Recovery Charge	$F = 9.4 \text{ A}, \text{ and } = 100 \text{ A/} \mu \text{s}$		5	10	nC

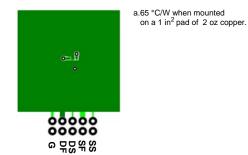
FDMA7628 Single N-Channel 1.5 V Specified PowerTrench[®] MOSFET

NOTES:

1. R_{BJA} is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R_{BJC} is guaranteed by design while R_{BJA} is determined by the user's board design.

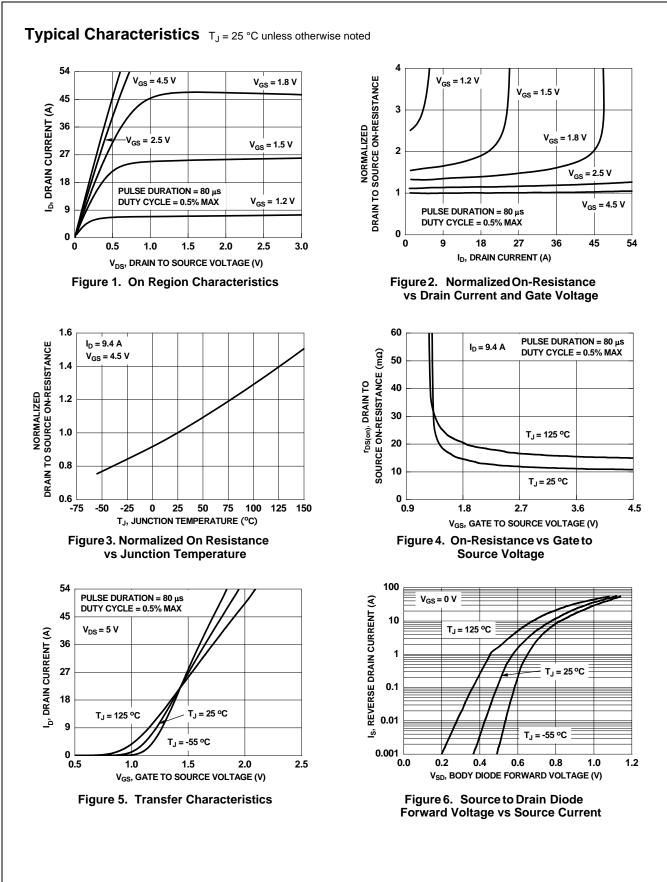
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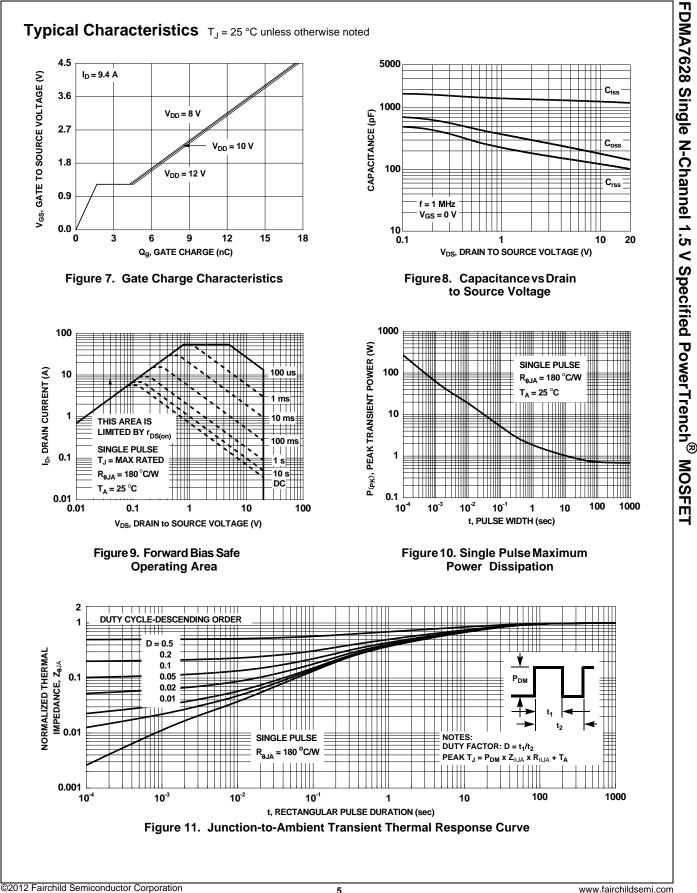


2. Pulse Test: Pulse Width < 300 μ s, Duty cycle < 2.0%.

b. 180 °C/W when mounted on a minimum pad of 2 oz copper.

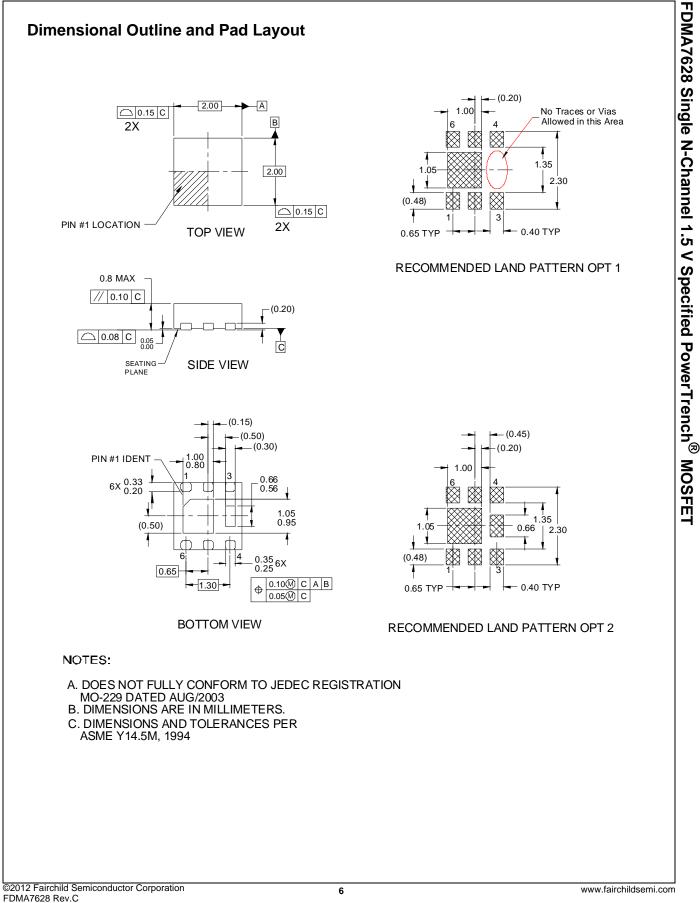


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